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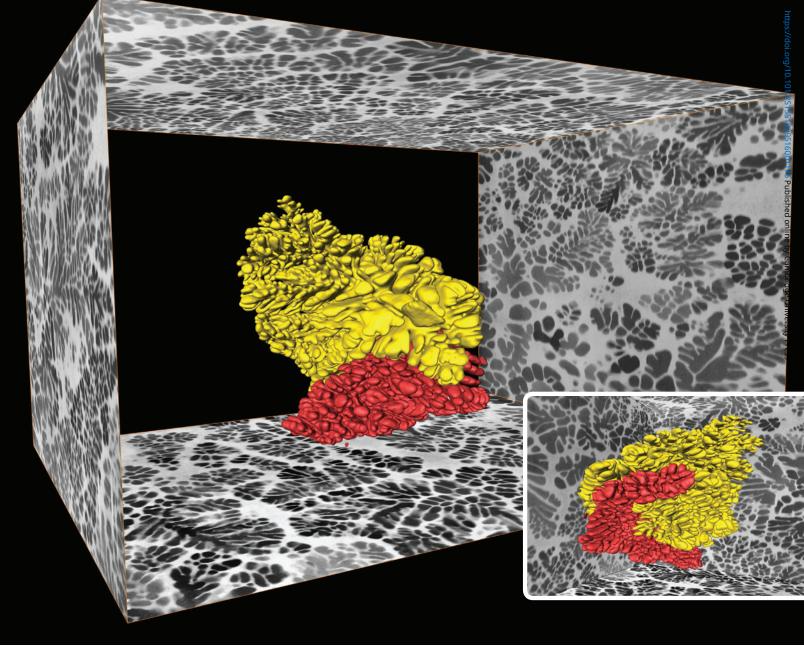
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FEI Avizo[®] 3D visualization of two large adjacent crystalline dendrites of a bulk-metallic-glass matrix composite ($Zr_{ses}Ti_{i43}Nb_{s2}Cu_{s1}Ni_{s9}Be_{10}$). Data was obtained by large volume serial sectioning tomography using the Helios PFIB DualBeam. The sectioned block is about 90×80×70 µm³. Sample from The University of Tennessee, USA. Images courtesy of The University of Manchester.

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Feature Article

12 Acceptance Angle Control for Improved Transmission Imaging in an SEM

Jason Holm and Robert R. Keller

X-ray Microanalysis

- 20 Ultra-Low kV EDS A New Approach to Improved Spatial Resolution, Surface Sensitivity, and Light Element Compositional Imaging and Analysis in the SEM Simon Burgess, James Sagar, James Holland, Xiaobing Li, and Frank Bauer
- **30** Advanced Chemical Analysis Using an Annular Four-Channel Silicon Drift Detector Ralf Terborg, Andi Kaeppel, Baojun Yu, Max Patzschke, Tobias Salge, and Meiken Falke
- **36** Large-Area Quantitative Phase Mapping in the Scanning Electron Microscope Keith Thompson
- **46** Improvements in SDD Efficiency From X-ray Counts to Data Tara Nylese and Jens Rafaelsen

Meeting Preview

54 Microscopy & Microanalysis 2017 in St. Louis, Missouri Jay Potts, Program Chair

Pioneers

56 Pioneers in Optics: Georges de Buffon Eric Clark

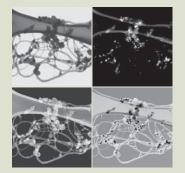
Departments

- 7 Editorial
- 8 Carmichael's Concise Review
- 58 Industry News
- 60 Product News
- 62 Microscopy and Microanalysis Highlights

64 NetNotes

- 69 Calendar of Meetings
- 73 Dear Abbe
- 74 Index of Advertisers

About the Cover



Contents

SEM images of single-wall carbon nanotube bundles with metal catalyst particles. Clockwise from upper left: brightfield STEM, high-angle annular darkfield STEM, marginal brightfield STEM, and secondary electron mode. Image width = 1 μ m.

See article by Holm and Keller

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